



THE DATASHEET OF HMC415LP3E





GaAs InGaP HBT MMIC POWER AMPLIFIER, 4.9 - 5.9 GHz

Typical Applications

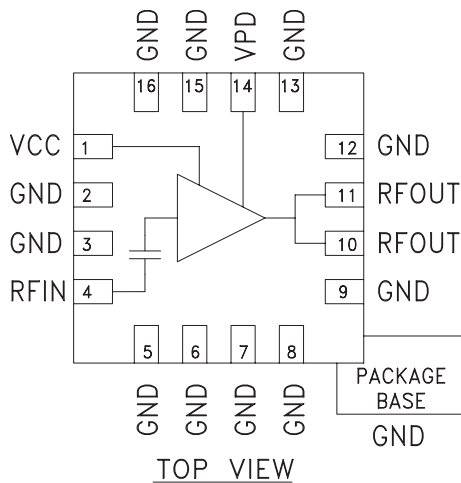
This amplifier is ideal for use as a power amplifier for 4.9 - 5.9 GHz applications:

- 802.11a WLAN
- HiperLAN WLAN
- Access Points
- UNII & ISM Radios

Features

- Gain: 20 dB
- 34% PAE @ Psat = +26 dBm
- 3.7% EVM @ Pout = +15 dBm with 54 Mbps OFDM Signal
- Supply Voltage: +3V
- Power Down Capability
- Low External Part Count

Functional Diagram



General Description

The HMC415LP3 & HMC415LP3E are high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC Power amplifiers which operate between 4.9 and 5.9 GHz. The amplifier is packaged in a low cost, leadless surface mount package with an exposed base for improved RF and thermal performance. With a minimum of external components, the amplifier provides 20 dB of gain, +26 dBm of saturated power, and 34% PAE from a +3V supply voltage. Vpd can be used for full power down or RF output power/current control. For +15 dBm OFDM output power (64 QAM, 54 Mbps), the HMC415LP3 & HMC415LP3E achieve an error vector magnitude (EVM) of 3.7% meeting 802.11a linearity requirements.

Electrical Specifications, $T_A = +25^\circ C$, $V_s = 3V$, $V_{pd} = 3V$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	4.9 - 5.1			5.1 - 5.4			5.4 - 5.9			GHz
Gain	18	20		18.5	20.5		16	19		dB
Gain Variation Over Temperature		0.04	0.05		0.04	0.05		0.04	0.05	dB / °C
Input Return Loss		10			9			8		dB
Output Return Loss		10			12			8		dB
Output Power for 1dB Compression (P1dB)	Icq = 285 mA Icq = 200 mA	20	22.5 22.0	20.5	23.0 22.5		18	21.5 21.0		dBm
Saturated Output Power (Psat)		25.5			26			24		dBm
Output Third Order Intercept (IP3)		28	31	29	32		27	30		dBm
Error Vector Magnitude (54 Mbps OFDM Signal @ +15 dBm Pout)	Icq = 200 mA				3.7					%
Noise Figure		6			6			6		dB
Supply Current (Icq)	Vpd = 0V/3V		0.002 / 285		0.002 / 285			0.002 / 285		mA
Control Current (Ipd)	Vpd = 3V		7		7			7		mA
Switching Speed	tOn, tOff		45		45			45		ns

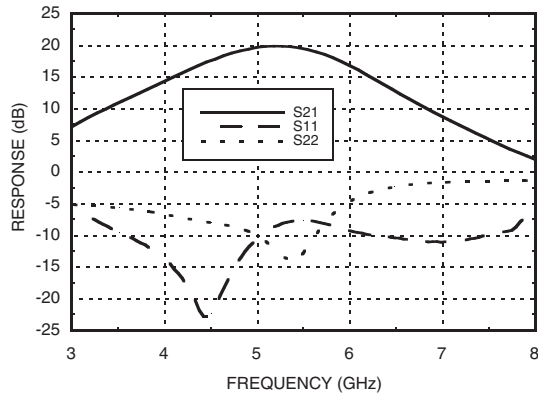
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

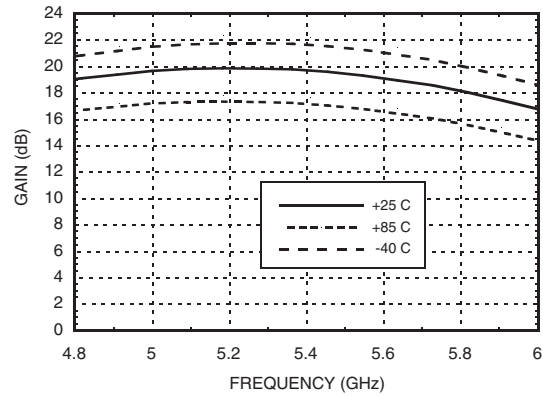


**GaAs InGaP HBT MMIC
POWER AMPLIFIER, 4.9 - 5.9 GHz**

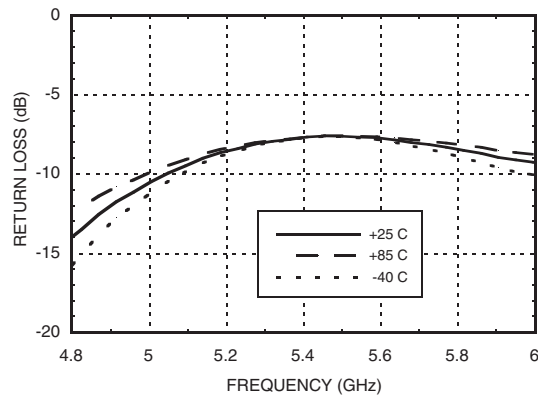
Broadband Gain & Return Loss



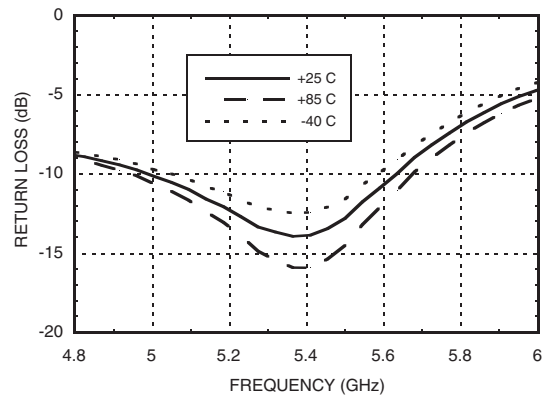
Gain vs. Temperature



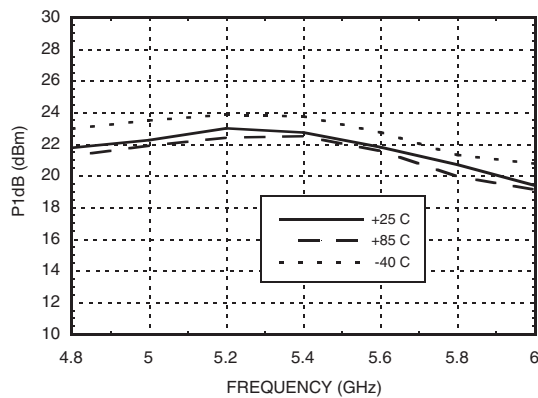
Input Return Loss vs. Temperature



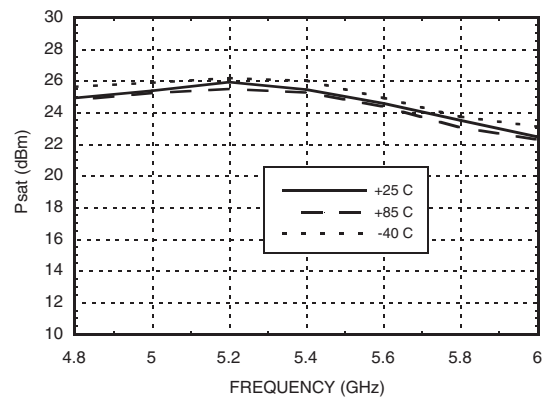
Output Return Loss vs. Temperature



P1dB vs. Temperature



Psat vs. Temperature



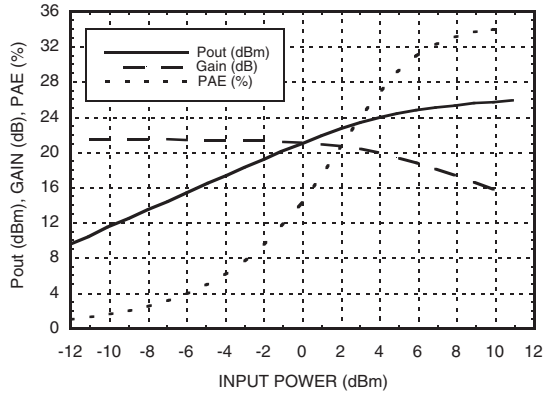
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

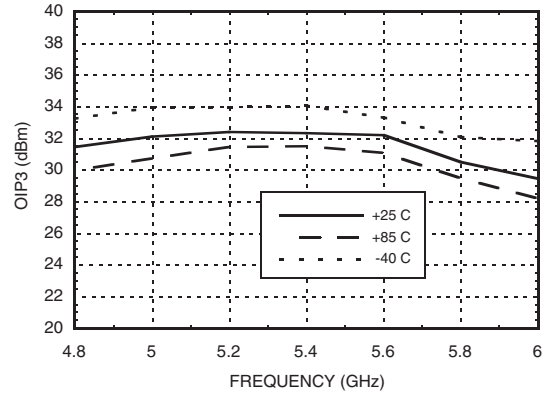


**GaAs InGaP HBT MMIC
POWER AMPLIFIER, 4.9 - 5.9 GHz**

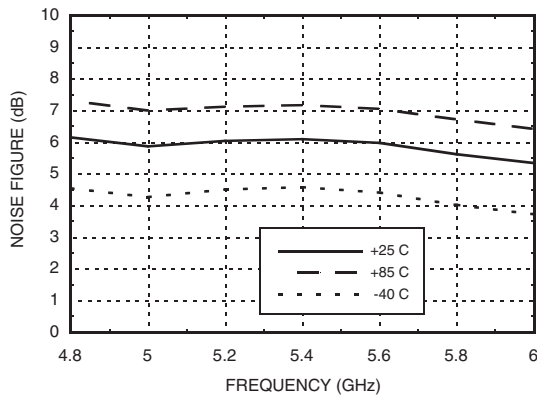
Power Compression @ 5.2 GHz



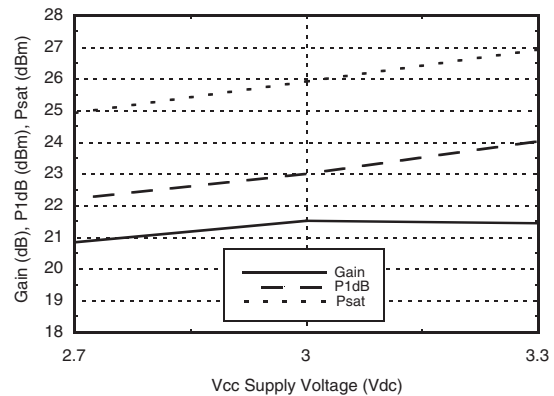
Output IP3 vs. Temperature



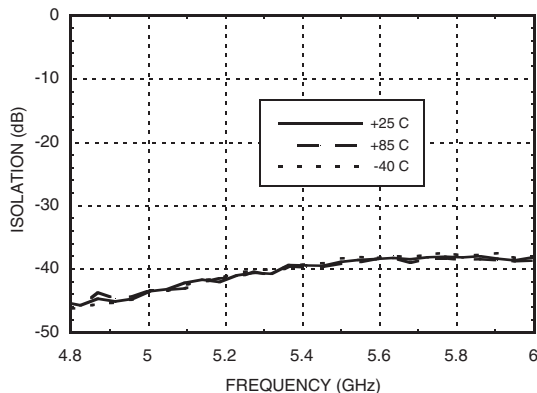
Noise Figure vs. Temperature



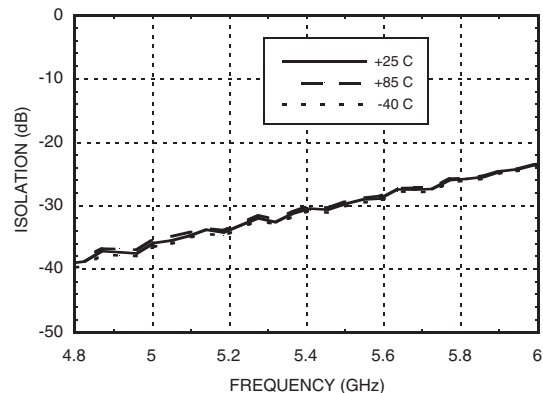
Gain & Power vs. Supply Voltage



Reverse Isolation vs. Temperature



Power Down Isolation vs. Temperature



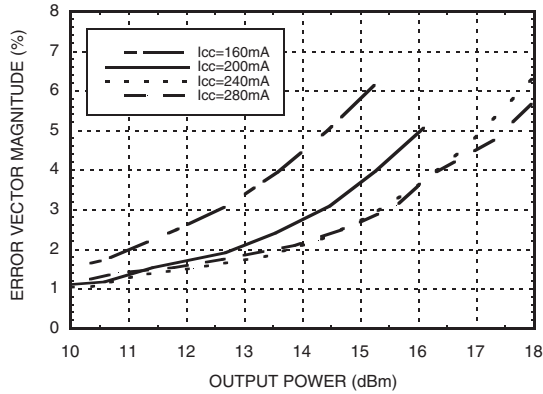
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

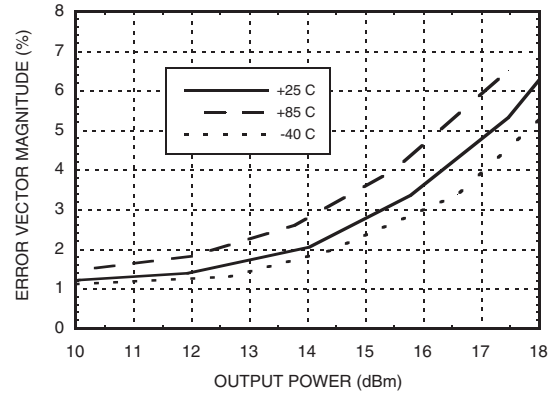


**GaAs InGaP HBT MMIC
POWER AMPLIFIER, 4.9 - 5.9 GHz**

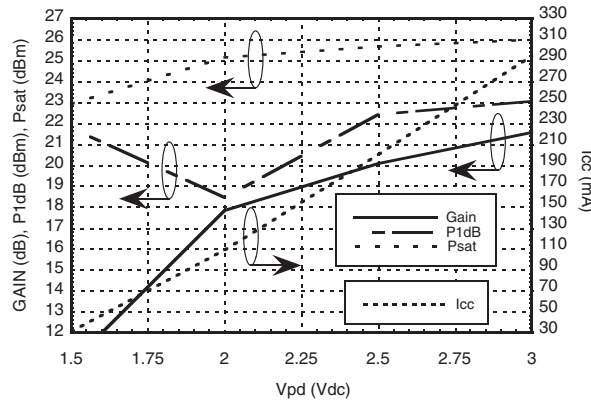
**EVM vs. Supply Current,
F = 5.2 GHz**



**EVM vs. Temperature,
I_{cc} = 240 mA, F = 5.2 GHz**



**Gain, Power & Quiescent
Supply Current vs. V_{pd} @ 5.2 GHz**



11

LINEAR & POWER AMPLIFIERS - SMT

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



GaAs InGaP HBT MMIC POWER AMPLIFIER, 4.9 - 5.9 GHz

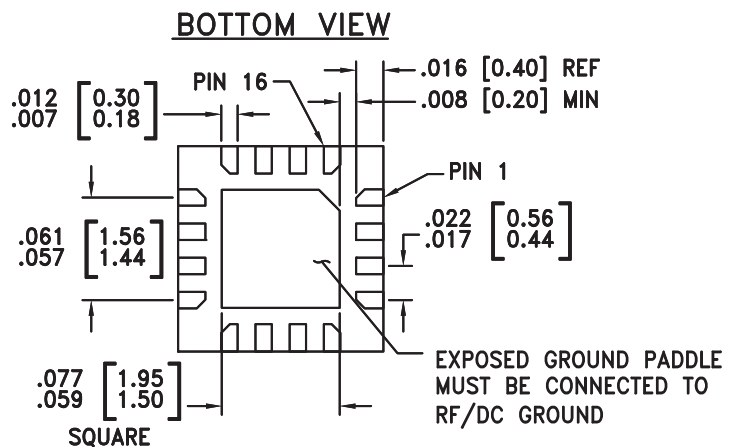
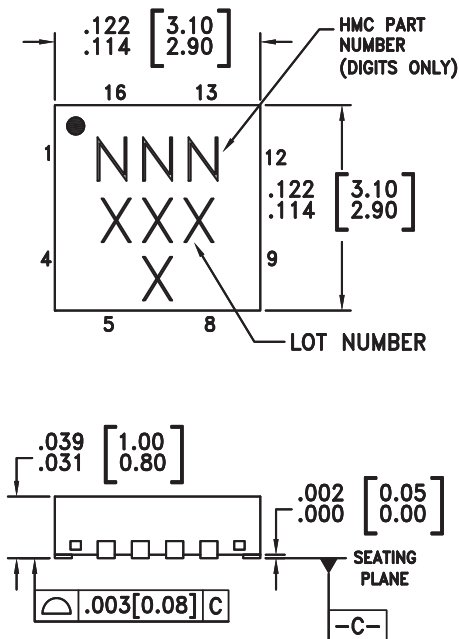
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+5Vdc
Control Voltage (Vpd)	+3.5 Vdc
RF Input Power (RFIN)(Vs = Vpd = +3.0 Vdc)	+13 dBm
Junction Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 17 mW/°C above 85 °C)	1.105 W
Thermal Resistance (junction to ground paddle)	59 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC415LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	415 XXXX
HMC415LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	415 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

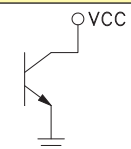

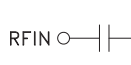
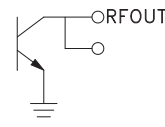
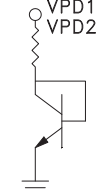
[3] 4-Digit lot number XXXX

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

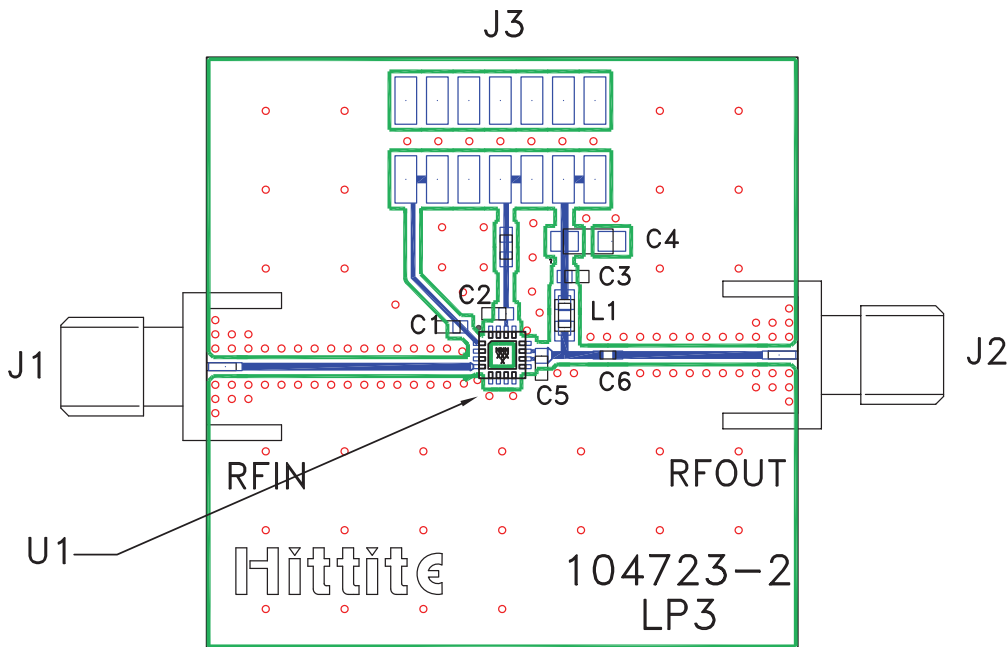


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vcc	Power supply voltage for the first amplifier stage. An external bypass capacitor of 330 pF is required as shown in the application schematic.	
2, 3, 5, 6, 7, 8, 9, 12, 13, 15, 16	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms from 5.0 to 6.0 GHz.	
10, 11	RFOUT	RF output and DC bias for the output stage.	
14	Vpd	Power control pin. For maximum power, this pin should be connected to 3.0V. A higher voltage is not recommended. For lower idle current, this voltage can be reduced.	



Evaluation PCB



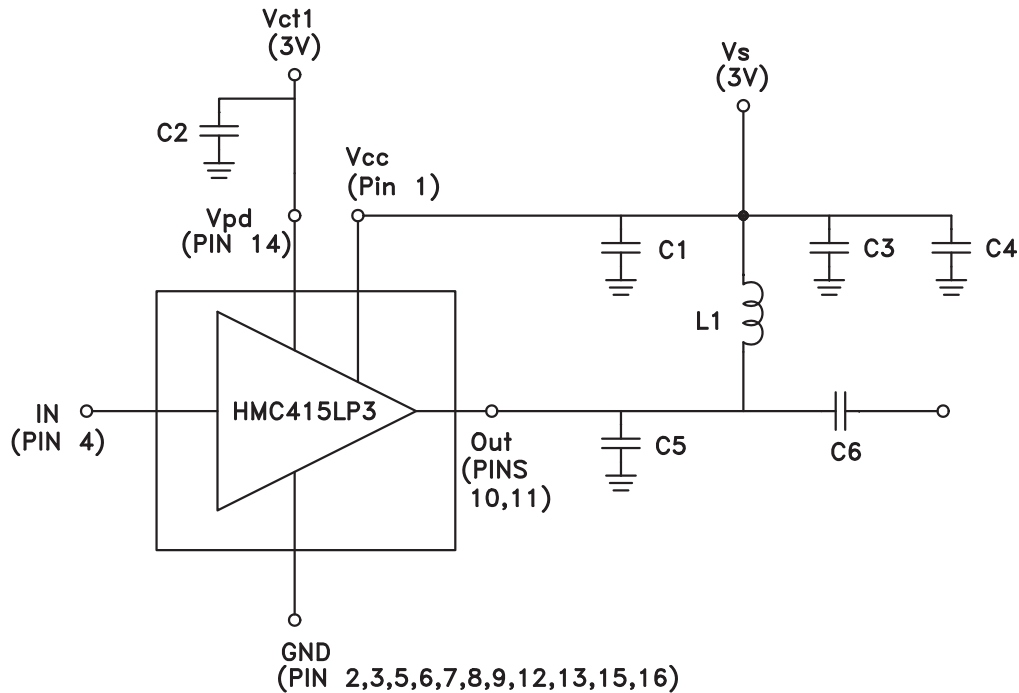
List of Materials for Evaluation PCB 105173 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	2 mm DC Header
C1 - C3	330 pF Capacitor, 0603 Pkg.
C4	2.2 μ F Capacitor, Tantalum
C5	0.5 pF Capacitor, 0603 Pkg.
C6	7.0 pF Capacitor, 0402 Pkg.
L1	3.0 nH Inductor, 0805 Pkg.
U1	HMC415LP3 / HMC415LP3E Amplifier
PCB [2]	104723 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.


**GaAs InGaP HBT MMIC
POWER AMPLIFIER, 4.9 - 5.9 GHz**
Application Circuit


Recommended Component Values	
L1	3.0 nH
C1, C2, C3	330 pF
C4	2.2 μ F
C5	0.5 pF
C6	7.0 pF

Note 1: C1 should be located < 0.1" (2.54mm) from Pin 1 (Vcc)

Note 2: C3 should be located < 0.1" (2.54mm) from L1.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View HMC415LP3E on WIN SOURCE](#)

 [Analog Devices Inc. Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management